

<b>ABSOLUTE MAXIMUM RATINGS<sup>1)</sup> TLMG310. ,TLMH310. TLMO310. ,TLMP310. ,TLMY310</b>				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_R$	6	V
DC forward current	$T_{amb} \leq 60\text{ }^\circ\text{C}$	$I_F$	30	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	$I_{FSM}$	0.5	A
Power dissipation	$T_{amb} \leq 60\text{ }^\circ\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	100	$^\circ\text{C}$
Operating temperature range		$T_{amb}$	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		$T_{stg}$	- 55 to + 100	$^\circ\text{C}$
Soldering temperature	$t \leq 5\text{ s}$	$T_{sd}$	260	$^\circ\text{C}$
Thermal resistance junction/ ambient	mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{thJA}$	400	K/W

Note:

<sup>1)</sup>  $T_{amb} = 25\text{ }^\circ\text{C}$ , unless otherwise specified

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> TLMH310., RED</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	$I_F = 10\text{ mA}$	TLMH3100	$I_V$	2.5	6		mcd
		TLMH3101	$I_V$	4		12.5	mcd
		TLMH3102	$I_V$	6.3		20	mcd
Dominant wavelength	$I_F = 10\text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10\text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10\text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20\text{ mA}$		$V_F$		2	2.8	V
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{amb} = 25\text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> In one packing unit  $I_{Vmax}/I_{Vmin} \leq 1.6$

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> TLMO310., SOFT ORANGE</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	$I_F = 10\text{ mA}$	TLMO3100	$I_V$	2.5	8		mcd
		TLMO3101	$I_V$	4		12.5	mcd
Dominant wavelength	$I_F = 10\text{ mA}$		$\lambda_d$	598		611	nm
Peak wavelength	$I_F = 10\text{ mA}$		$\lambda_p$		605		nm
Angle of half intensity	$I_F = 10\text{ mA}$		$\varphi$		$\pm 60$		deg
Forward voltage	$I_F = 20\text{ mA}$		$V_F$		2	2.8	V
Reverse voltage	$I_R = 10\text{ }\mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1\text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{amb} = 25\text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> In one packing unit  $I_{Vmax}/I_{Vmin} \leq 1.6$



<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> TLMY310., YELLOW</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	$I_F = 10 \text{ mA}$	TLMY3100	$I_V$	2.5	6		mcd
		TLMY3102	$I_V$	6.3		20	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.1	2.8	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> In one packing unit  $I_{Vmax}/I_{Vmin} \leq 1.6$

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> TLMG310., GREEN</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	$I_F = 10 \text{ mA}$	TLMG3100	$I_V$	4	9		mcd
		TLMG3102	$I_V$	10		20	mcd
		TLMG3105	$I_V$	6.3		20	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.2	2.8	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> In one packing unit  $I_{Vmax}/I_{Vmin} \leq 1.6$

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> TLMP310., PURE GREEN</b>							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity <sup>2)</sup>	$I_F = 10 \text{ mA}$	TLMP3100	$I_V$	1	4		mcd
		TLMP3101	$I_V$	1.6		5	mcd
		TLMP3102	$I_V$	2.5		8	mcd
		TLMP3107	$I_V$	2.5		5	mcd
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	555		565	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		555		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.1	2.8	V
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$		$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{amb} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<sup>2)</sup> In one packing unit  $I_{Vmax}/I_{Vmin} \leq 1.6$

### TYPICAL CHARACTERISTICS

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

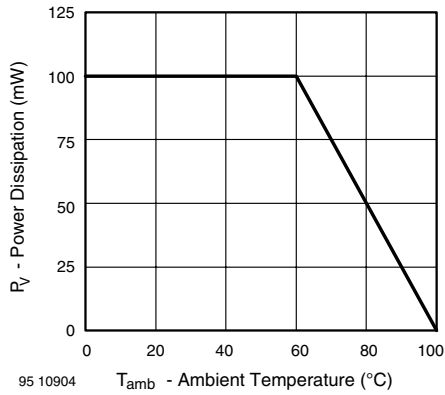


Figure 1. Power Dissipation vs. Ambient Temperature

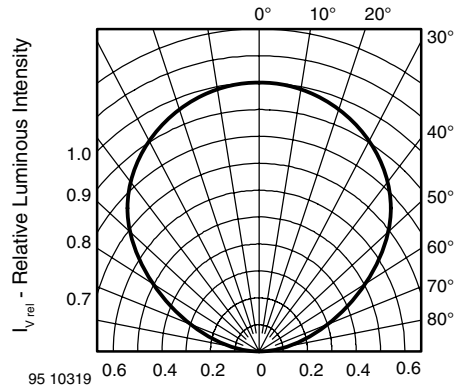


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

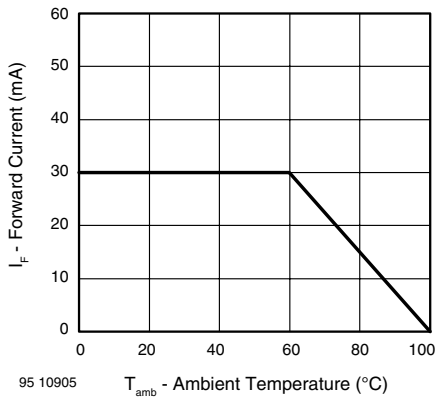


Figure 2. Forward Current vs. Ambient Temperature for InGaN

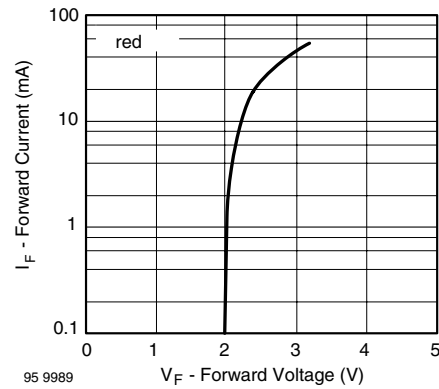


Figure 5. Forward Current vs. Forward Voltage

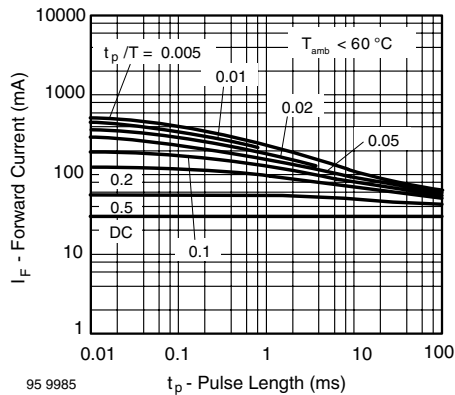


Figure 3. Pulse Forward Current vs. Pulse Duration

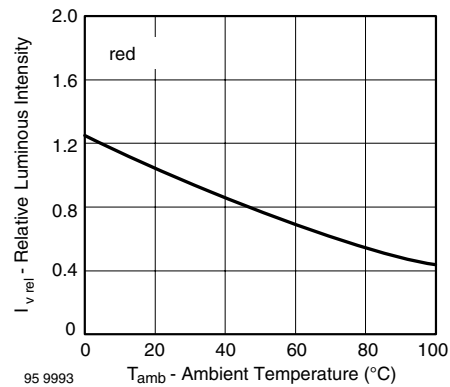


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

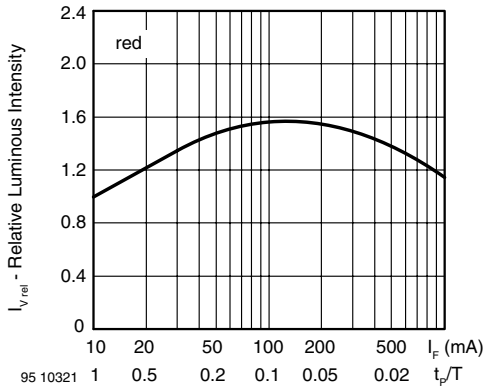


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

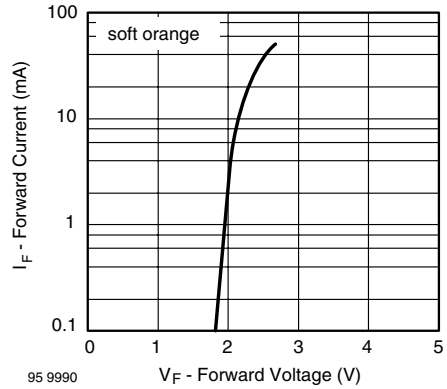


Figure 10. Forward Current vs. Forward Voltage

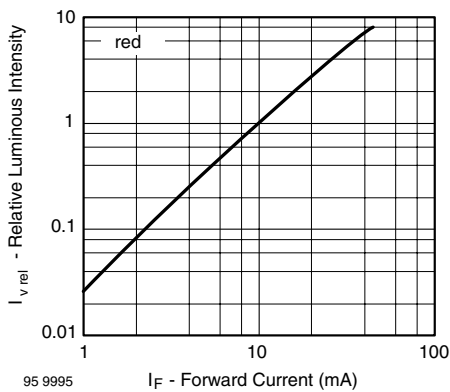


Figure 8. Relative Luminous Intensity vs. Forward Current

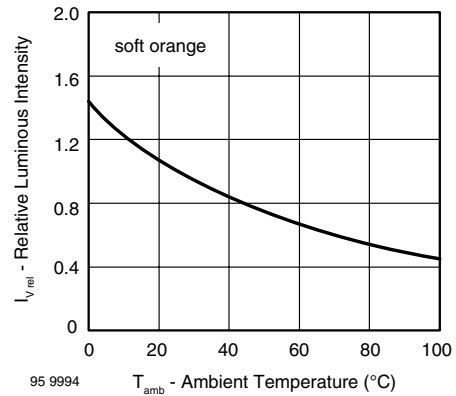


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

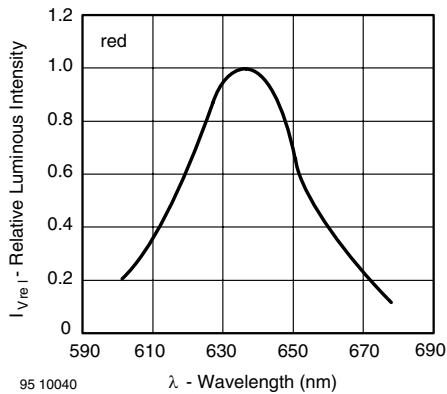


Figure 9. Relative Intensity vs. Wavelength

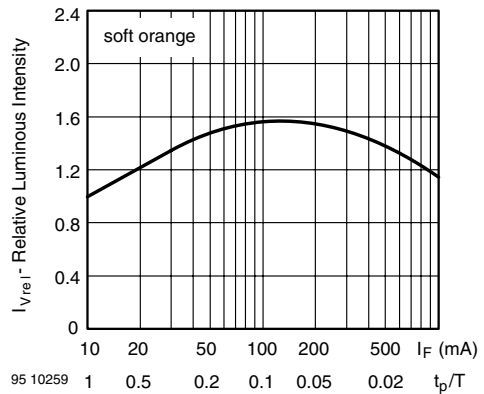


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

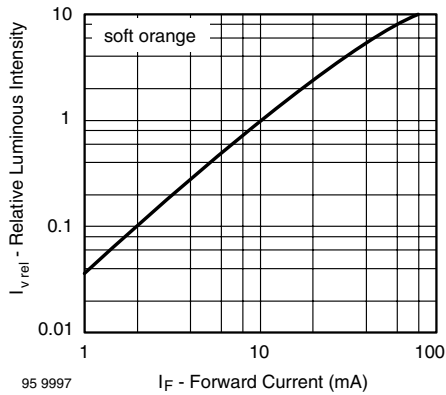


Figure 13. Relative Luminous Intensity vs. Forward Current

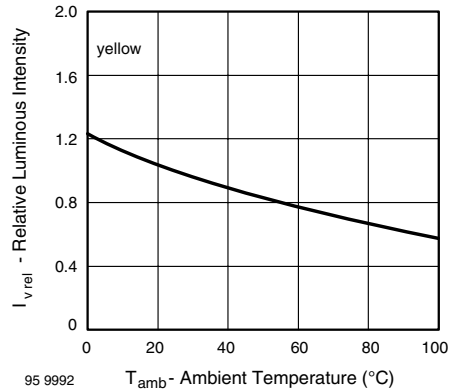


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

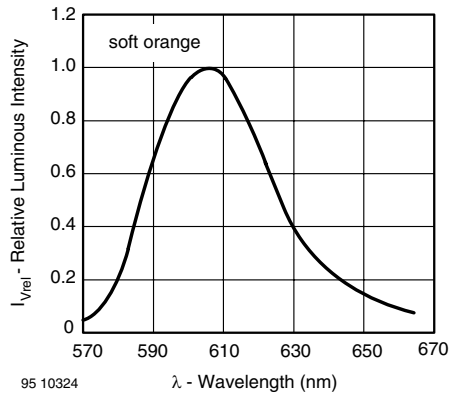


Figure 14. Relative Intensity vs. Wavelength

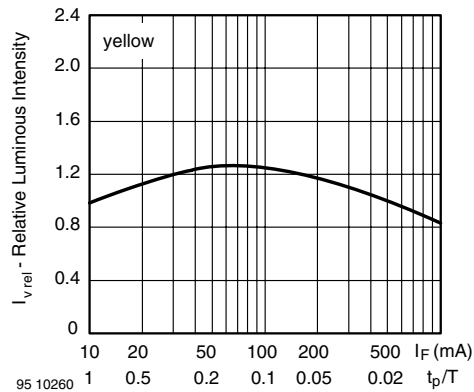


Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

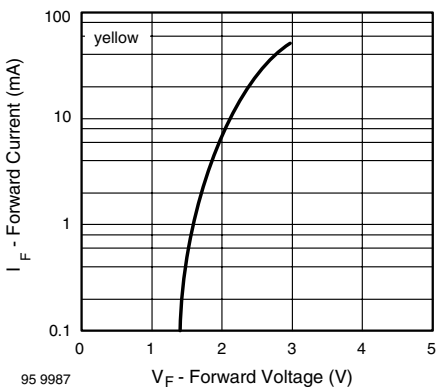


Figure 15. Forward Current vs. Forward Voltage

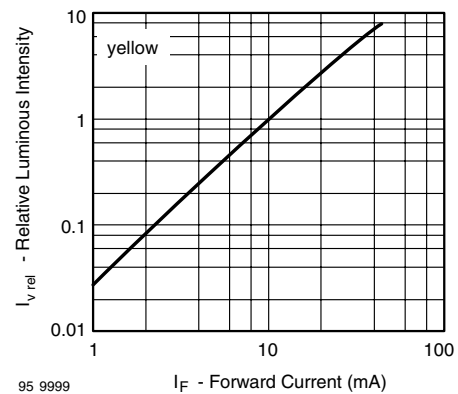


Figure 18. Relative Luminous Intensity vs. Forward Current

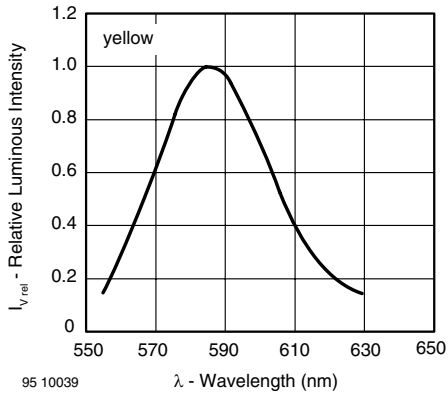


Figure 19. Relative Intensity vs. Wavelength

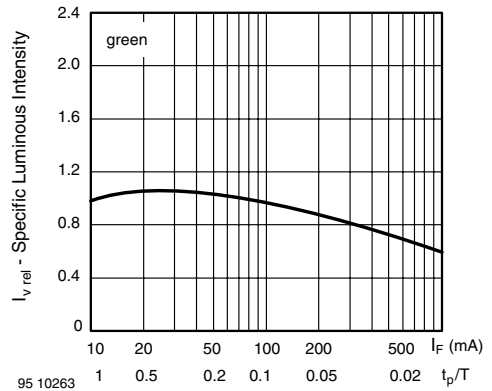


Figure 22. Specific Luminous Intensity vs. Forward Current

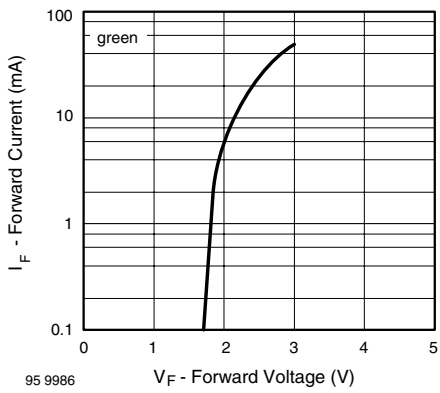


Figure 20. Forward Current vs. Forward Voltage

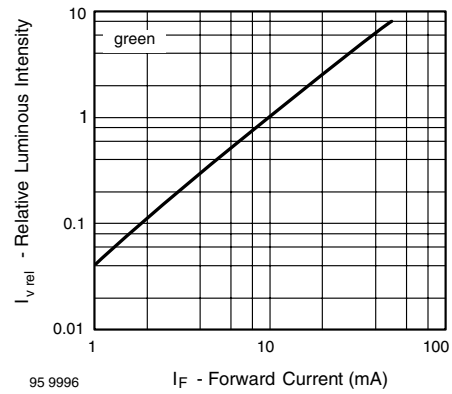


Figure 23. Relative Luminous Intensity vs. Forward Current

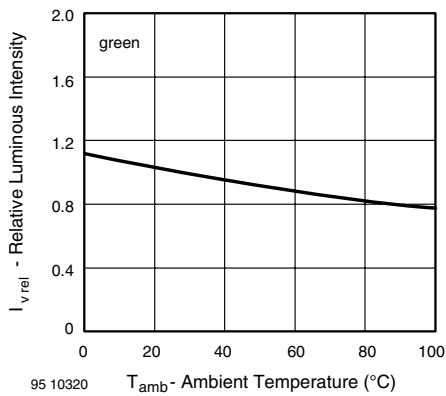


Figure 21. Rel. Luminous Intensity vs. Ambient Temperature

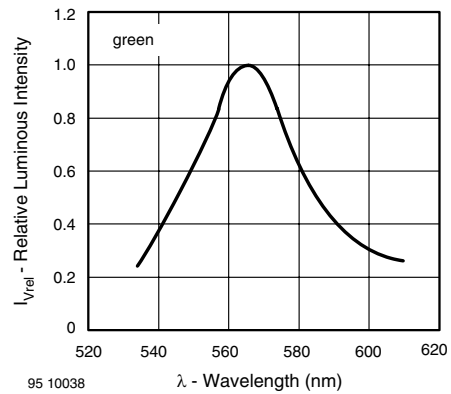


Figure 24. Relative Intensity vs. Wavelength

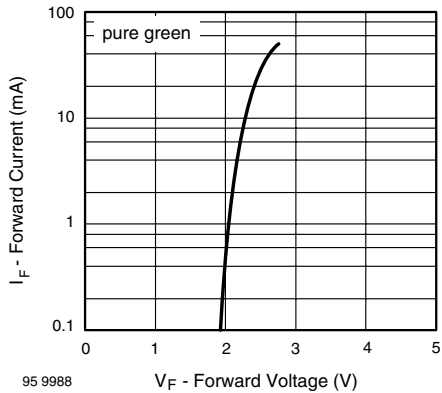


Figure 25. Forward Current vs. Forward Voltage

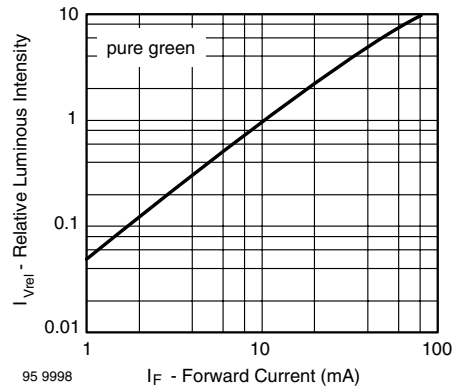


Figure 28. Relative Luminous Intensity vs. Forward Current

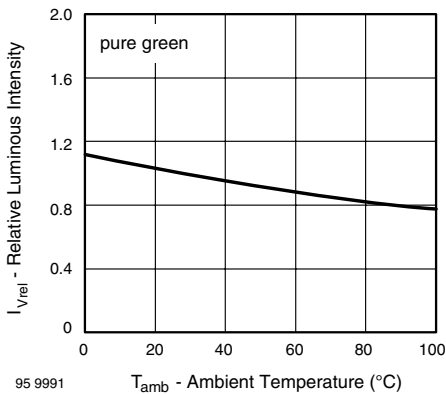


Figure 26. Rel. Luminous Intensity vs. Ambient Temperature

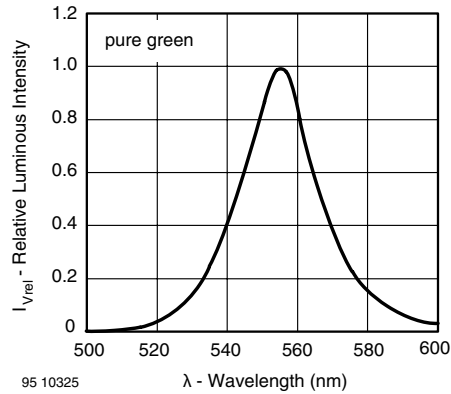


Figure 29. Relative Intensity vs. Wavelength

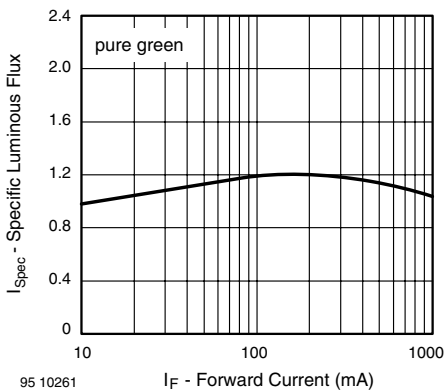
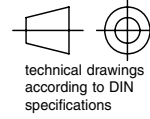
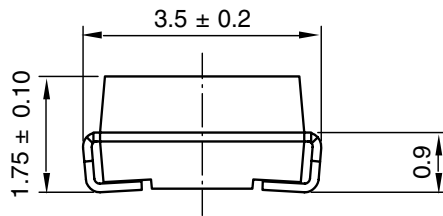
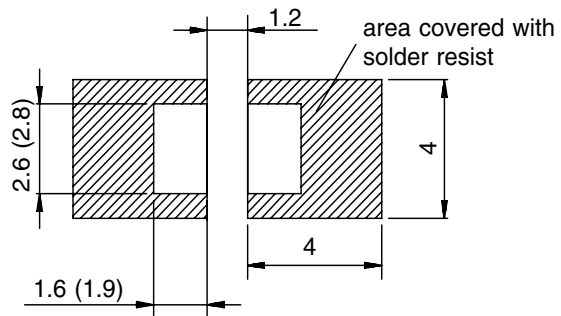
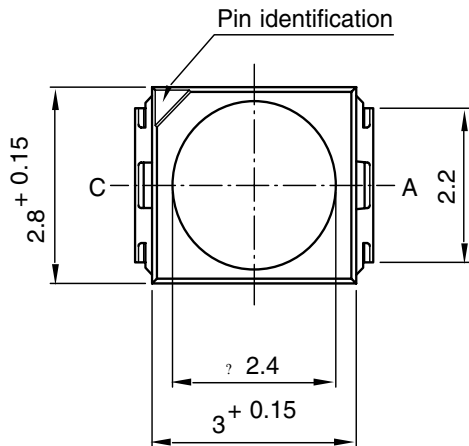


Figure 27. Specific Luminous Intensity vs. Forward Current

**PACKAGE DIMENSIONS** in millimeters



**Mounting Pad Layout**



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95 11314-1



**Vishay Semiconductors****Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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